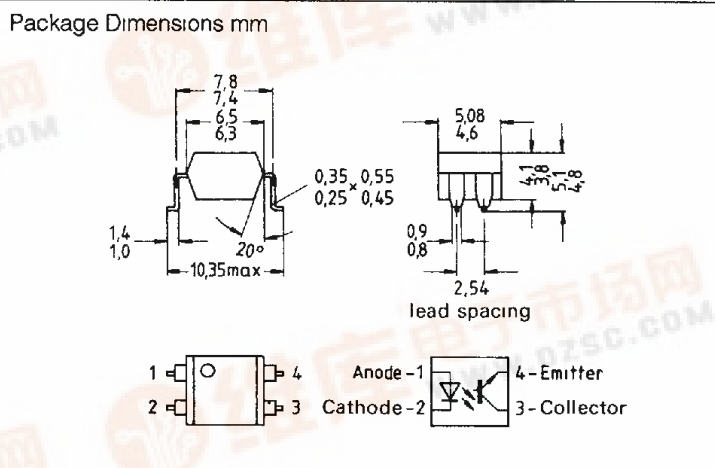
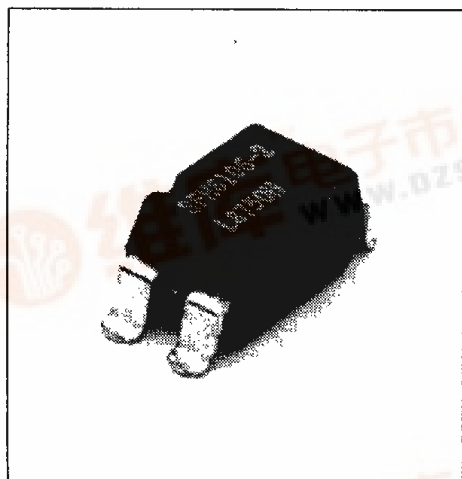


SIEMENS

SFH 6106  
T-41-83

2.8 kV TRIOS® OPTOCOUPLERS  
HIGH RELIABILITY



FEATURES

- Isolation Test Voltage: 2800 V
- High Current Transfer Ratios  
at 10 mA: 40-320%  
at 1 mA: 13-90%
- Short Switching Times
- Minor CTR Degradation
- 100% Burn-In
- Field-Effect Stable by TRIOS
- Temperature Stable
- Good CTR Linearity Depending on Forward Current
- High Collector-Emitter Voltage  
 $V_{CE0}=70\text{ V}$
- Low Saturation Voltage
- Low Coupling Capacitance
- High Common-Mode Interference Immunity
- UL Approval #52744

DESCRIPTION

The optically coupled isolator SFH 6106 features a high current transfer ratio, low coupling capacitance, and high isolation voltage. As emitter it employs a GaAs infrared emitting diode which is optically coupled with a silicon planar phototransistor acting as detector.

The component is incorporated in a plastic plug-in DIP-4 package. The bent terminal pins are suitable for surface mounting (SMD).

The coupling device permits to transfer signals between two electrically isolated circuits. The potential difference between the circuits to be coupled is not allowed to exceed the maximum permissible reference voltages

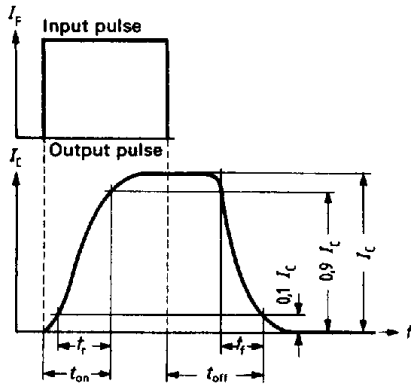
\*Transparent IO Shield

Optocouplers  
(Optoisolators)





**Switching times**



The figure above defines the following times:

**Turn-on time (t<sub>ON</sub>)**

The turn-on time  $t_{ON}$  is the time in which the output current (collector current)  $I_C$  rises to 90% of its maximum value after activation of the drive current  $I_F$ .

The rise time  $t_r$  is the time in which the collector current  $I_C$  rises from 10% to 90% of its final value.

**Turn-off time (t<sub>OFF</sub>)**

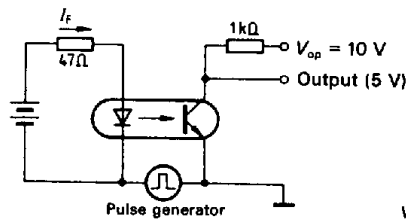
The turn-off time  $t_{OFF}$  is the time in which the collector current  $I_C$  drops to 10% of its maximum value after deactivation of the drive current  $I_F$ .

The fall time  $t_f$  is the time in which the collector current  $I_C$  drops from 90% to 10% of its maximum value.

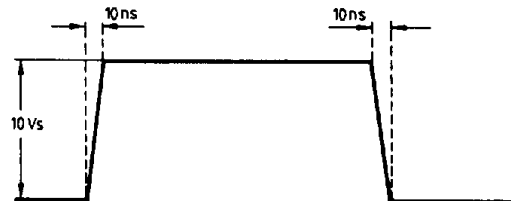
**Common-mode interference immunity**

Changes in the potential difference between emitter and detector are transferred to the output (collector-emitter) in form of an interference pulse via the coupling capacitance. Optocouplers without base contacting feature a substantially improved common-mode interference immunity, since in this case the part of the load that is coupled in the base connection and additionally intensified by the transistor power gain (B typ. 400) is dropped to a large degree. A further improvement may be obtained by a capacitance between collector and emitter, which hardly influences the switching time, if adequately dimensioned.

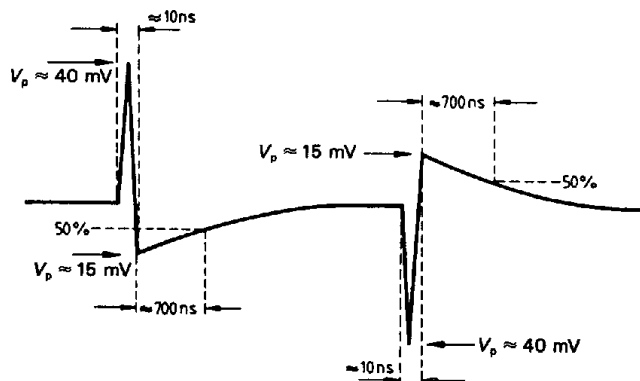
**Measuring set-up for pulse diagrams**



**Input pulse (pulse generator)**

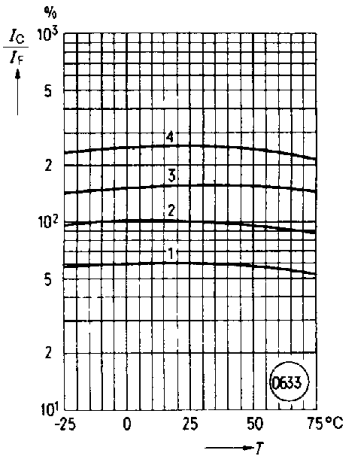


**Output pulse (typical)**

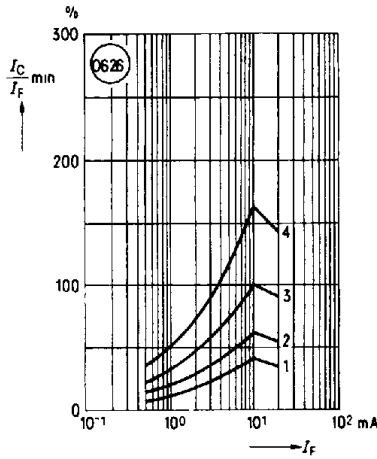


Optocouplers (Optoisolators)

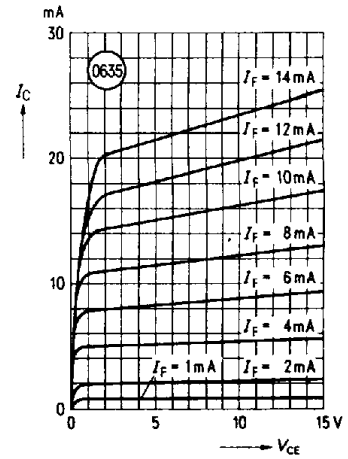
**Current transfer ratio (typ.) versus temperature**  
( $I_F = 10 \text{ mA}$ ,  $V_{CE} = 5 \text{ V}$ )



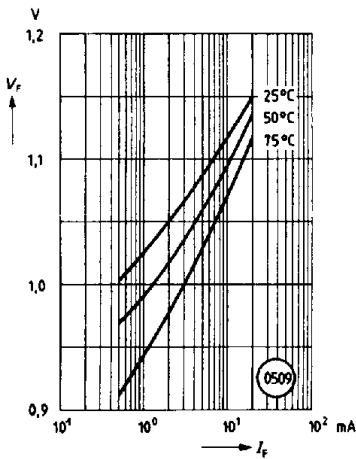
**Minimum current transfer ratio versus diode forward current**  
( $T_A = 25^{\circ}\text{C}$ ,  $V_{CE} = 5 \text{ V}$ )



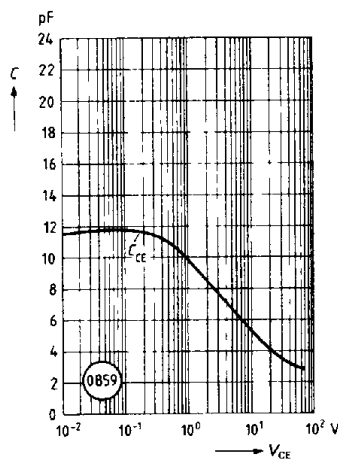
**Output characteristics (typ.)**  
Collector current versus collector-emitter voltage (typ.)  
( $T_A = 25^{\circ}\text{C}$ )



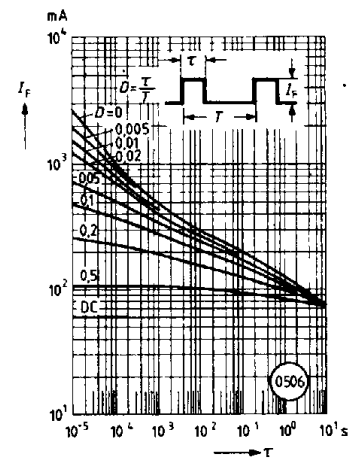
**Forward voltage (typ.) of the diode versus forward current**



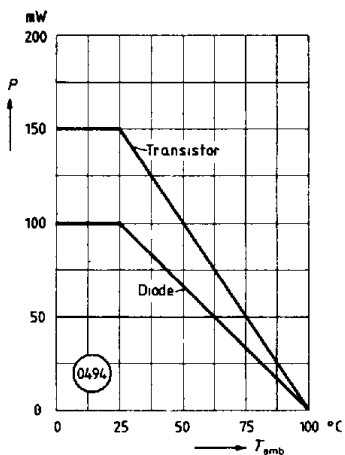
**Transistor capacitance (typ.) versus emitter voltage**  
( $T_A = 25^{\circ}\text{C}$ ,  $f = 1 \text{ MHz}$ )



**Permissible pulse handling capability**  
Forward current versus pulse width  
( $D = \text{parameter}$ ,  $T_A = 25^{\circ}\text{C}$ )



**Permissible power dissipation for transistor and diode versus ambient temperature**



**Permissible forward current of the diode versus ambient temperature**

